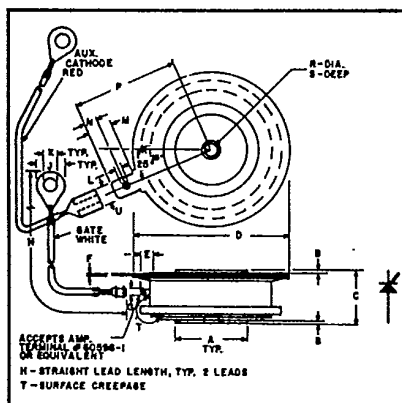


**C380__X555**

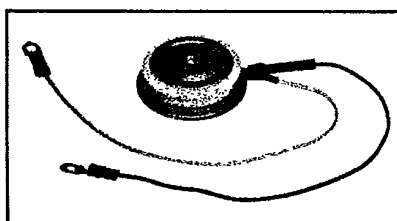
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Powerex, Inc. Hillis Street, Youngwood, Pennsylvania 15697 (412) 925-7272

Powerex Europe, S.A., 428 Ave. G. Durand, BP107, 72003 LeMans, France (43) 72.75.15

Phase Control SCR**300 Amperes Avg****100-1300 Volts****TO-200
Outline Drawing**

Dimensions	Inches		Millimeters	
	Min.	Max.	Min.	Max.
A	.744	.752	18.897	19.101
B	.030	.060	.762	1.524
C	.515	.565	13.081	14.351
D	1.600	1.656	40.64	42.06
E	.110	—	2.794	—
F	.013	.017	.330	.432
G	.057	.059	1.447	1.449
H	7.980	8.115	202.70	206.11
J	—	.300	—	7.620
K	.137	.153	3.479	3.886
L	.065	.070	1.651	1.778
M	.245	.260	6.223	6.604
N	.120	.140	3.048	3.556
P	1.090	1.125	27.69	28.55
R	.135	.145	3.429	3.683
S	.067	.083	1.701	2.108
T	.340	—	8.636	—
U	.186	.189	4.724	4.801

**C380__X555
Phase Control SCR
300 Amperes/100-1300 Volts****Description**

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak (Pow-R-Disc) devices employing the field-proven amplifying (di/namic) gate.

Features:

- ☐ Low On-State Voltage
- ☐ High di/dt
- ☐ High dv/dt
- ☐ Hermetic Packaging
- ☐ Excellent Surge and I²t Ratings
- ☐ High Temperature Operation

Applications:

- ☐ Power Supplies
- ☐ Battery Chargers
- ☐ Motor Control
- ☐ Light Dimmers
- ☐ VAR Generators

Ordering Information

Example: Select the complete nine or ten digit part number you desire from the table - i.e. C380NX555 is an 800 Volt, 300 Ampere Phase Control SCR.

Type	Voltage		Current
	V _{ORM} V _{RRM}	Code	
C380__X555	100	A	300
	200	B	
	300	C	
	400	D	
	500	E	
	600	M	
	700	S	
	800	N	
	900	T	
	1000	P	
	1100	PA	
	1200	PB	
	1300	PC	



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C380_X555

Phase Control SCR

300 Amperes Avg/100-1300 Volts

Absolute Maximum Ratings

	Symbol	C380_X555	Units
RMS On-State Current	$I_{T(RMS)}$	450	Amperes
Average On-State Current	$I_{T(av)}$	300	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM}	3200	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}	2900	Amperes
Critical Rate-of-Rise of On-State Current (Non-Repetitive)	di/dt	600	Amperes/ μs
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt	300	Amperes/ μs
I^2t (for Fusing), 8.3 milliseconds	I^2t	42,000	A ² sec
Peak Gate Power Dissipation	P_{GM}	10	Watts
Average Gate Power Dissipation	$P_{G(av)}$	2	Watts
Storage Temperature	T_{STG}	-40 to 150	°C
Operating Temperature	T_J	-40 to 150	°C
Mounting Force [Ⓢ]		720 to 880	lb.
Mounting Force [Ⓢ]		3.2 to 3.92	kN

Electrical and Thermal Characteristics

Characteristics	Symbol	Test Conditions	C380_X555	Units
Voltage—Blocking State Maximums				
Forward Leakage, Peak	I_{DRM}	$T_J = 150^\circ C, V = V_{DRM}$	45	mA
Reverse Leakage, Peak	I_{RRM}	$T_J = 150^\circ C, V = V_{RRM}$	45	mA
Current—Conducting State Maximums				
Peak On-State Voltage	V_{TM}	$I_{TM} = 1500A$ Peak, $T_C = 25^\circ C$	2.85	Volts
Switching				
Typical Turn-Off Time	t_q	$T_J = +150^\circ C, I_{TM} = 250$ Amperes, $V_R = 50$ Volts Minimum, V_{DRM} (Reapplied), Rate-of-Rise of Reapplied Off-State voltage = 20 Volts/ μsec (Linear) Gate Bias During Turn-off Interval = 0 Volts, 100 Ω . Duty Cycle $\leq 0.01\%$	75	μsec
Typical Delay Time	t_d	$T_C = +25^\circ C, I_T = 100$ Adc, $V_{DRM} =$ Rated Gate Supply: 10 Volt Open Circuit, 25 ohm, 0.1 μsec maximum rise time	1.0	μsec
Min. Critical dv/dt exponential to V_{DRM}	dv/dt	$T_J = 150^\circ C$, Gate Open	200	V/ μsec
Thermal				
Maximum Thermal Resistance, [Ⓢ] double sided cooling				
Junction to Case	$R_{\theta JC}$		.095	°C/Watt
Case to Sink, Lubricated	$R_{\theta CS}$		.02	°C/Watt
Gate—Maximum Parameters				
Gate Current to Trigger	I_{GT}	$T_C = 25^\circ C, V_D = 6Vdc, R_L = 3\Omega$	150	mA
Gate Voltage to Trigger	V_{GT}	$T_C = -40^\circ C$ to $150^\circ C, V_D = 6 Vdc, R_L = 3\Omega$	3	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_J = 150^\circ C, R_L = 1000\Omega$, Rated V_{DRM}	.15	Volts
Peak Forward Gate Current	I_{GTM}		10	Amperes
Peak Reverse Gate Voltage	V_{GRM}		5	Volts

Ⓢ Consult recommended mounting procedures.



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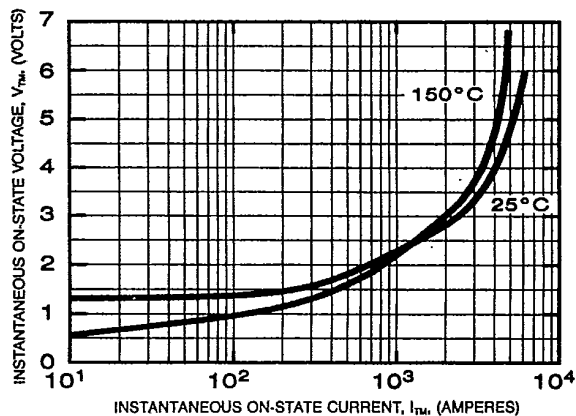
Powerex Europe, S.A., 428 Ave. G. Durand, BP107, 72003 LeMans, France (43) 72.75.15

C380-X555

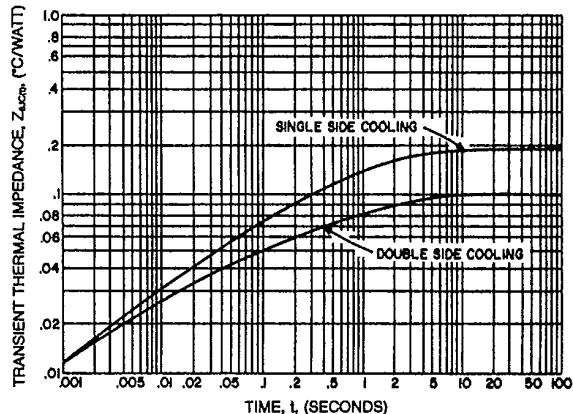
Phase Control SCR

300 Amperes Avg/100-1300 Volts

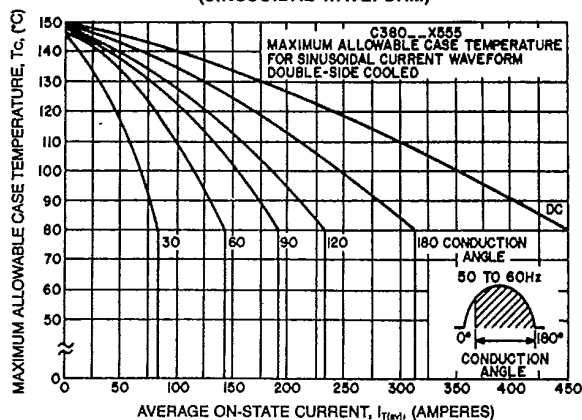
MAXIMUM ON-STATE CHARACTERISTICS



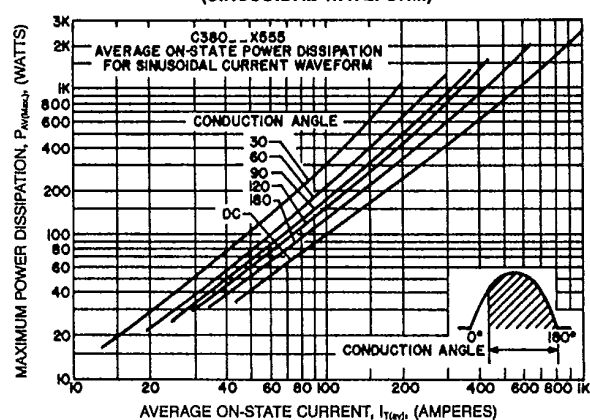
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



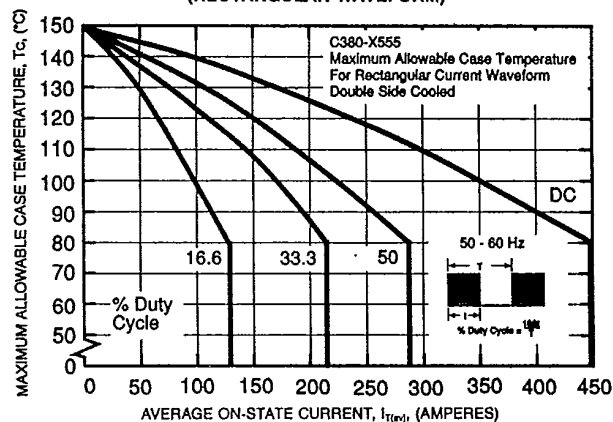
MAXIMUM ALLOWABLE CASE TEMPERATURE (SINUSOIDAL WAVEFORM)



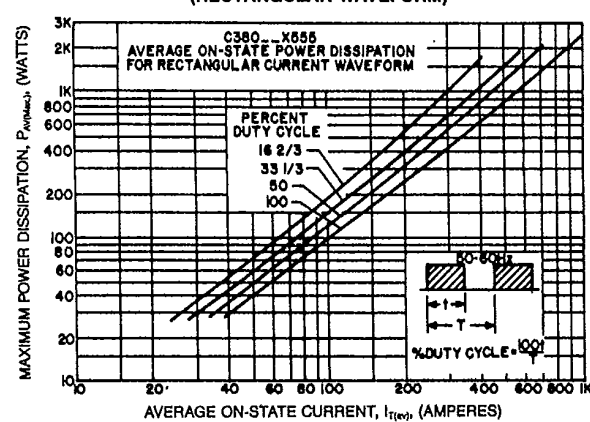
MAXIMUM ON-STATE POWER DISSIPATION (SINUSOIDAL WAVEFORM)



MAXIMUM ALLOWABLE CASE TEMPERATURE (RECTANGULAR WAVEFORM)



MAXIMUM ON-STATE POWER DISSIPATION (RECTANGULAR WAVEFORM)





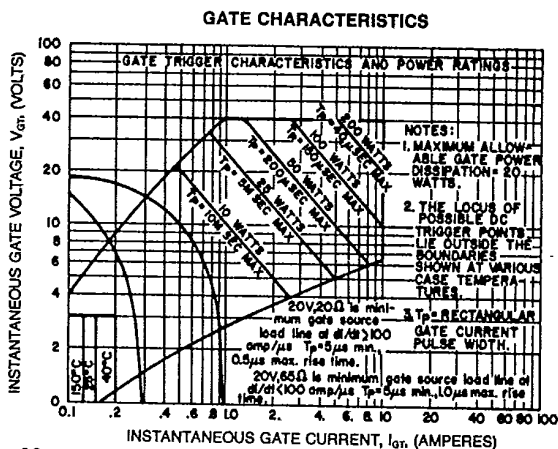
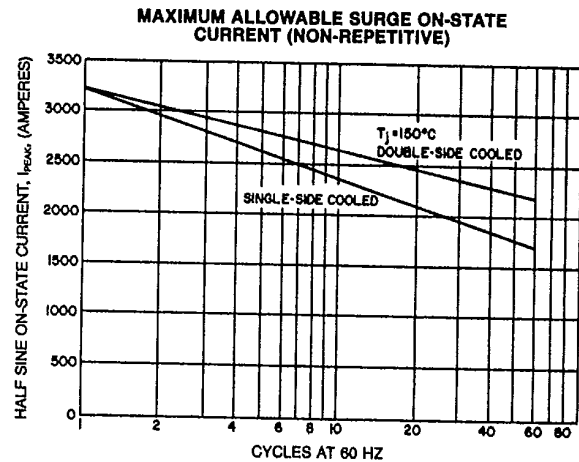
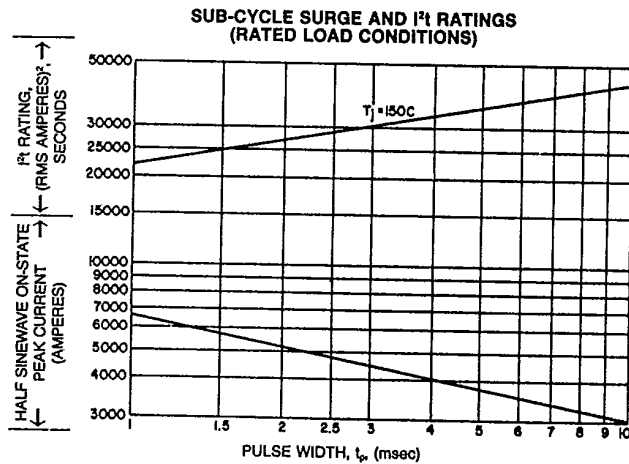
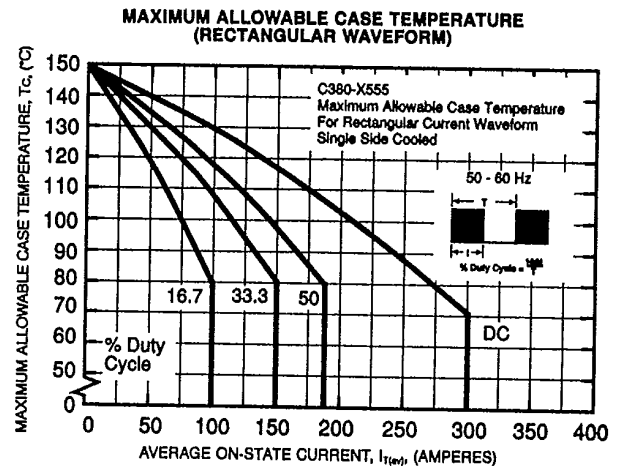
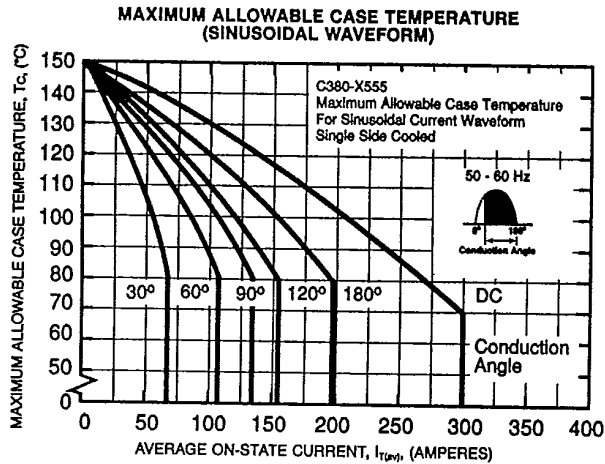
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C380-X555

Phase Control SCR

300 Amperes Avg/100-1300 Volts



- NOTES:
1. Maximum allowable gate power dissipation = 2 watts.
 2. The locus of possible DC trigger points lie outside the boundaries shown at various case temperatures.
 3. T_p = Rectangular Gate Current Pulse Width.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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